# EPC2007C – Enhancement Mode Power Transistor

 $V_{DS}$ , 100 V  $R_{DS(on)}$ , 30 m $\Omega$ I<sub>D</sub>, 6 A

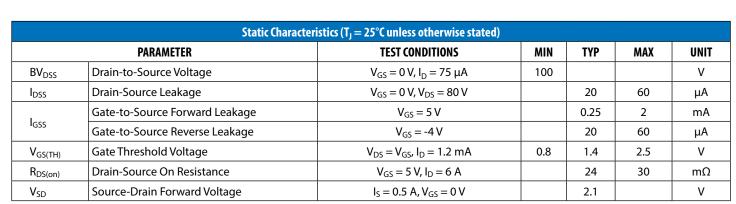


Gallium Nitride's exceptionally high electron mobility and low temperature coefficient allows very low R<sub>DS(on)</sub>, while its lateral device structure and majority carrier diode provide exceptionally low Q<sub>G</sub> and zero Q<sub>RR</sub>. The end result is a device that can handle tasks where very high switching frequency, and low on-time are beneficial as well as those where on-state losses dominate.

Maximum Ratings						
	PARAMETER	VALUE	UNIT			
V <sub>DS</sub>	Drain-to-Source Voltage (Continuous)	100	V			
	Continuous ( $T_A = 25^{\circ}C, R_{\theta JA} = 62^{\circ}C/W$ )	6	A			
I <sub>D</sub>	Pulsed (25°C, T <sub>PULSE</sub> = 300 μs)	40				
V	Gate-to-Source Voltage	6	V			
V <sub>GS</sub>	Gate-to-Source Voltage	-4				
٦	Operating Temperature	-40 to 150	°C			
T <sub>STG</sub>	Storage Temperature	-40 to 150				

Thermal Characteristics						
PARAMETER		ТҮР	UNIT			
R <sub>θJC</sub>	Thermal Resistance, Junction-to-Case	3.6				
R <sub>θJB</sub>	Thermal Resistance, Junction-to-Board	9.3	°C/W			
R <sub>θJA</sub>	Thermal Resistance, Junction-to-Ambient (Note 1)	80				

Note 1: R<sub>0JA</sub> is determined with the device mounted on one square inch of copper pad, single layer 2 oz copper on FR4 board. See https://epc-co.com/epc/documents/product-training/Appnote\_Thermal\_Performance\_of\_eGaN\_FETs.pdf for details.



All measurements were done with substrate connected to source.



EPC2007C



EPC2007C eGaN® FETs are supplied only in passivated die form with solder bumps

#### Applications

- High Speed DC-DC conversion
- Class-D Audio
- Wireless Power Transfer
- Lidar

#### Benefits

- Ultra High Efficiency
- Zero Q<sub>RR</sub>
- Ultra Low Q<sub>G</sub>
- Ultra Small Footprint

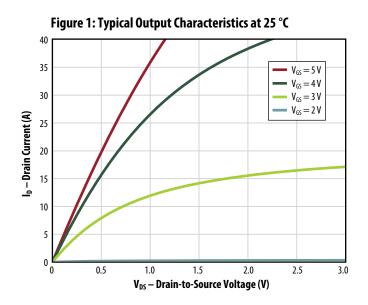
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Dynamic Characteristics (T <sub>J</sub> = 25°C unless otherwise stated)								
	PARAMETER	TEST CONDITIONS	MIN	ТҮР	MAX	UNIT		
C <sub>ISS</sub>	Input Capacitance			170	220	pF		
C <sub>RSS</sub>	Reverse Transfer Capacitance	$V_{DS} = 50 \text{ V}, V_{GS} = 0 \text{ V}$		1.9	2.7			
C <sub>OSS</sub>	Output Capacitance			110	165			
$R_G$	Gate Resistance			0.4		Ω		
$Q_G$	Total Gate Charge	$V_{DS} = 50 \text{ V}, V_{GS} = 5 \text{ V}, I_D = 6 \text{ A}$		1.6	2.2			
$Q_{GS}$	Gate-to-Source Charge			0.6				
$Q_{GD}$	Gate-to-Drain Charge	$V_{DS} = 50 \text{ V}, I_D = 6 \text{ A}$		0.3	0.6	- 6		
Q <sub>G(TH)</sub>	Gate Charge at Threshold			0.4		nC		
Q <sub>OSS</sub>	Output Charge	$V_{DS} = 50 \text{ V}, V_{GS} = 0 \text{ V}$		8.3	12.5			
Q <sub>RR</sub>	Source-Drain Recovery Charge			0				

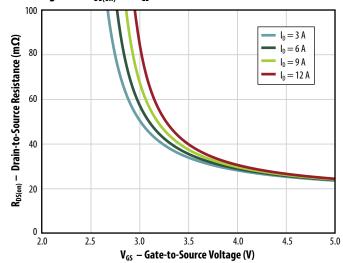
All measurements were done with substrate connected to source.

Note 2:  $C_{OSS(ER)}$  is a fixed capacitance that gives the same stored energy as  $C_{OSS}$  while  $V_{DS}$  is rising from 0 to 50% BV<sub>DSS</sub>.

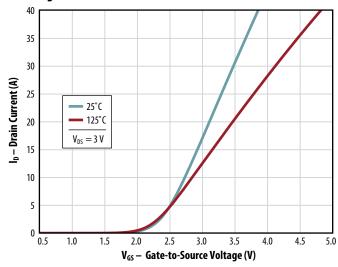
Note 3: C<sub>OSS(TR)</sub> is a fixed capacitance that gives the same charging time as C<sub>OSS</sub> while V<sub>DS</sub> is rising from 0 to 50% BV<sub>DSS</sub>.



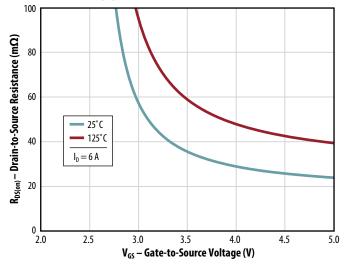


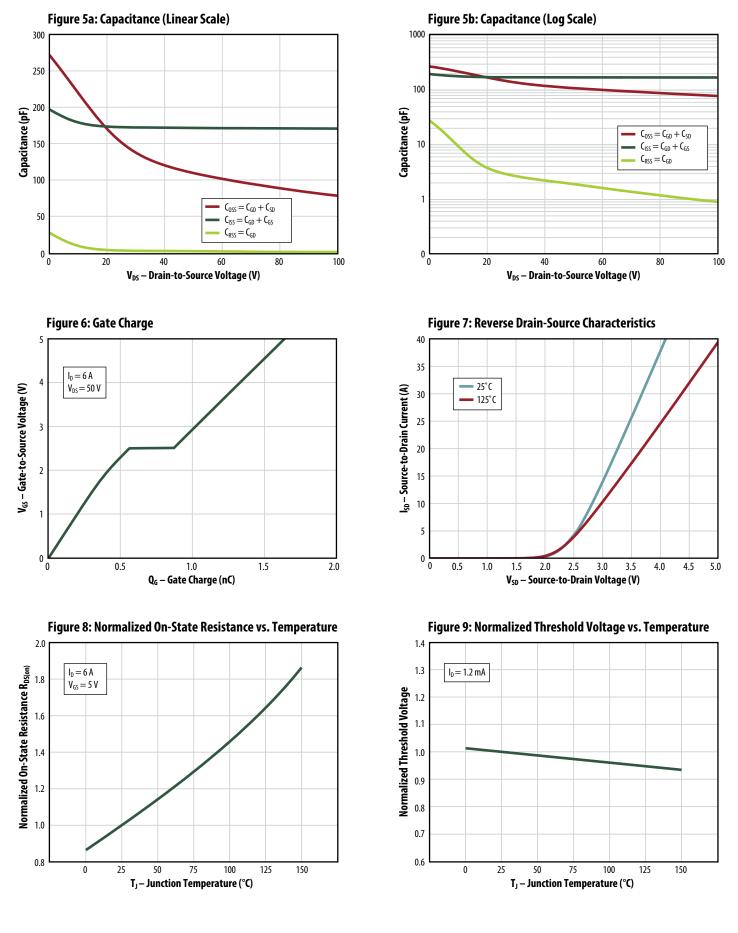


**Figure 2: Transfer Characteristics** 







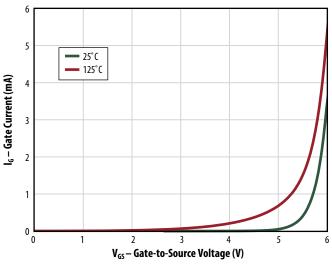


All measurements were done with substrate shortened to source.

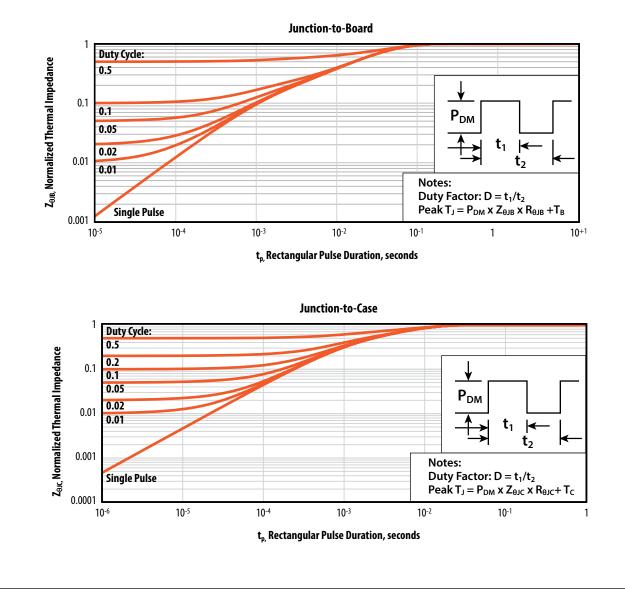
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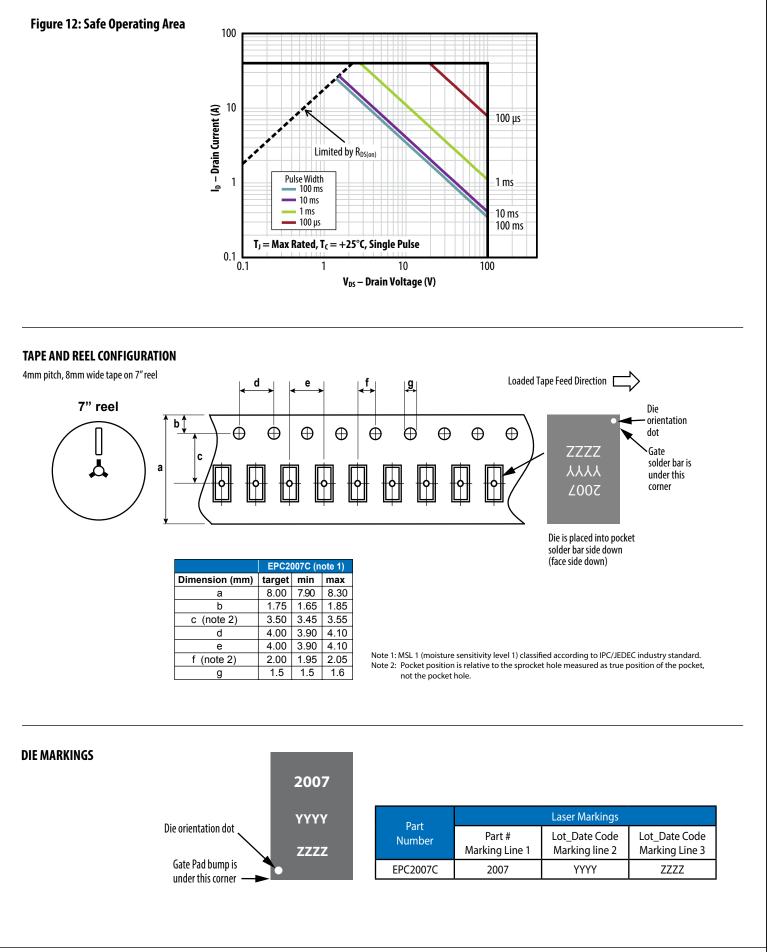
#### Figure 10: Gate Leakage Current

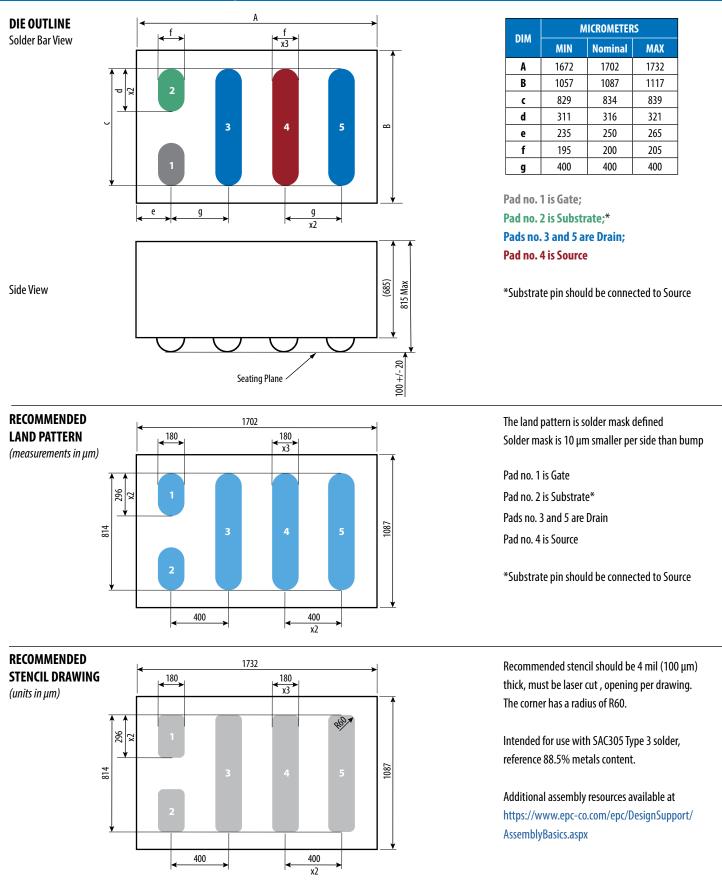


#### Figure 11: Transient Thermal Response Curves



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